

HIGH VOLTAGE SWITCHING APPLICATION.

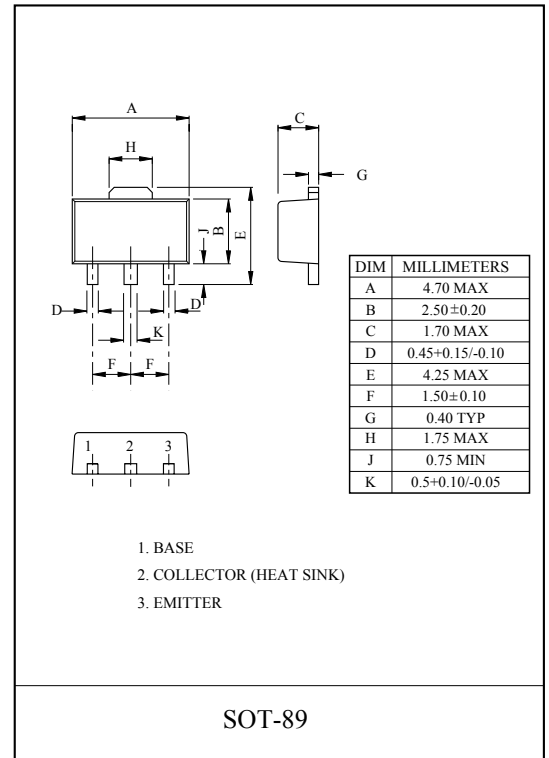
### FEATURES

- High Voltage :  $V_{CE0}=150V$ .
- High Transition Frequency :  $f_T=120MHz(Typ.)$ .
- 1W (Monunted on Ceramic Substrate).
- Small Flat Package.
- Complementary to KTA1660.

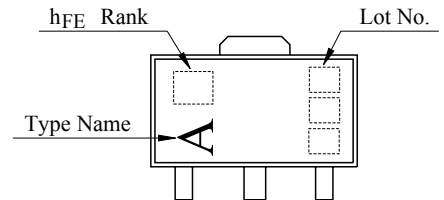
### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	200	V
Collector-Emitter Voltage	$V_{CEO}$	150	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	50	mA
Base Current	$I_B$	10	mA
Collector Power Dissipation	$P_C$	500	mW
	$P_C^*$	1	W
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C

$P_C^*$  : KTC4372 mounted on ceramic substrate (250mm<sup>2</sup>x0.8t)



### Marking



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=200V, I_E=0$	-	-	0.1	μA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$	-	-	0.1	μA
DC Current Gain	$h_{FE} (Note)$	$V_{CE}=5V, I_C=10mA$	70	-	240	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=1mA$	-	-	0.5	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE}=5V, I_C=30mA$	-	-	1.0	V
Transition Frequency	$f_T$	$V_{CE}=30V, I_C=10mA$	-	120	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0, f=1MHz$	-	3.5	5.0	pF

Note :  $h_{FE}$  Classification    O:70 ~ 140,    Y:120 ~ 240

